

Amendments to the Claims:

This listing of claims will replace all prior versions and listings of claims in the application.

1. (Original) A semiconductor structure comprising:
 - a semiconductor substrate;
 - at least one first crystalline epitaxial layer on said substrate, said first layer having a surface which is planarized; and
 - at least one second crystalline epitaxial layer on said at least one first layer.
- 2-34. (Cancelled)